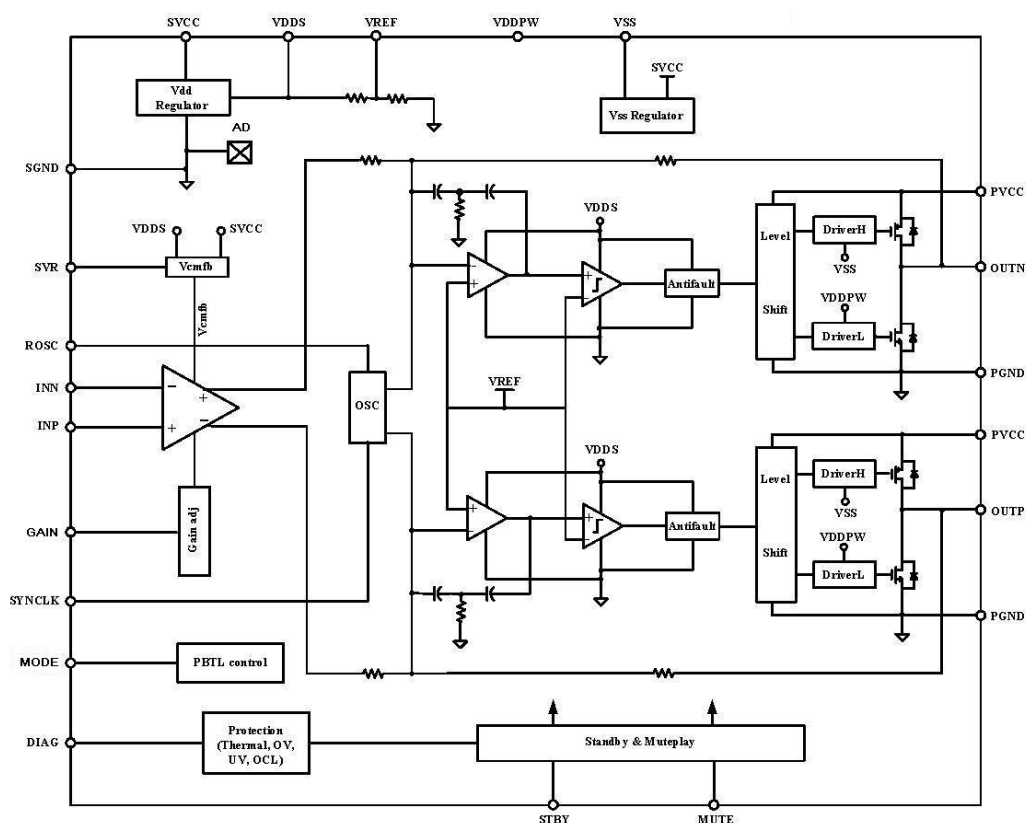


1 Device block diagram

The figure below shows the block diagram of one of the two identical channels of the TDA7498E.

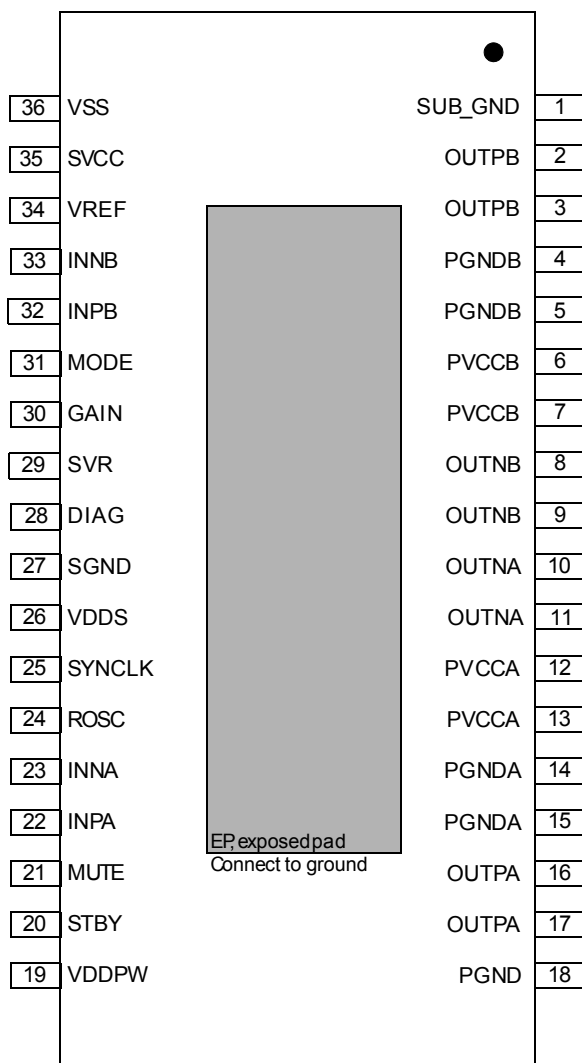
Figure 1. Internal block diagram (showing one channel only)



2 Pin description

2.1 Pinout

Figure 2. Pin connections (top view, PCB view)



2.2 Pin list

Table 1. Pin description list

Number	Name	Type	Description
1	SUB_GND	PWR	Connect to the frame
2,3	OUTPB	O	Positive PWM for right channel
4,5	PGNDB	PWR	Power stage ground for right channel
6,7	PVCCB	PWR	Power supply for right channel
8,9	OUTNB	O	Negative PWM output for right channel
10,11	OUTNA	O	Negative PWM output for left channel
12,13	PVCCA	PWR	Power supply for left channel
14,15	PGNDA	PWR	Power stage ground for left channel
16,17	OUTPA	O	Positive PWM output for left channel
18	PGND	PWR	Power stage ground
19	VDDPW	O	3.3-V (nominal) regulator output referred to ground for power stage
20	STBY	I	Standby mode control
21	MUTE	I	Mute mode control
22	INPA	I	Positive differential input of left channel
23	INNA	I	Negative differential input of left channel
24	ROSC	O	Master oscillator frequency-setting pin
25	SYNCLK	I/O	Clock in/out for external oscillator
26	VDDS	O	3.3-V (nominal) regulator output referred to ground for signal blocks
27	SGND	PWR	Signal ground
28	DIAG	O	Open-drain diagnostic output
29	SVR	O	Supply voltage rejection
30	GAIN	I	Gain setting input
31	MODE	I	Enables stereo or mono BTL mode of operation
32	INPB	I	Positive differential input of right channel
33	INNB	I	Negative differential input of right channel
34	VREF	O	Half VDDS (nominal) referred to ground
35	SVCC	PWR	Signal power supply
36	VSS	O	3.3-V (nominal) regulator output referred to power supply
-	EP	-	Exposed pad for heatsink, to be connected to ground

3 Electrical specifications

3.1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	DC supply voltage for pins PVCCA, PVCCB, SVCC	45	V
V_I	Voltage limits for input pins STBY, MUTE, INNA, INPA, INNB, INPB, GAIN, MODE	-0.3 to 4.0	V
T_j	Operating junction temperature	0 to 150	°C
T_{op}	Operating ambient temperature	0 to 70	°C
T_{stg}	Storage temperature	-40 to 150	°C

3.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Min.	Typ.	Max.	Unit
$R_{th\ j-case}$	Thermal resistance, junction to case	-	3.0		°C/W

3.3 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply voltage for pins PVCCA, PVCCB, SVCC	14	-	39	V
T_{amb}	Ambient operating temperature	0	-	70	°C

3.4 Electrical specifications

Unless otherwise stated, the values in the table below are specified for the conditions: $V_{CC} = 36\text{ V}$, $R_L = 4\ \Omega$, $R_{OSC} = R_3 = 39\text{ k}\Omega$, $C_8 = 100\text{ nF}$, $f = 1\text{ kHz}$, $G_V = 23.6\text{ dB}$ $T_{amb} = 25\text{ °C}$.

Table 5. Electrical specifications

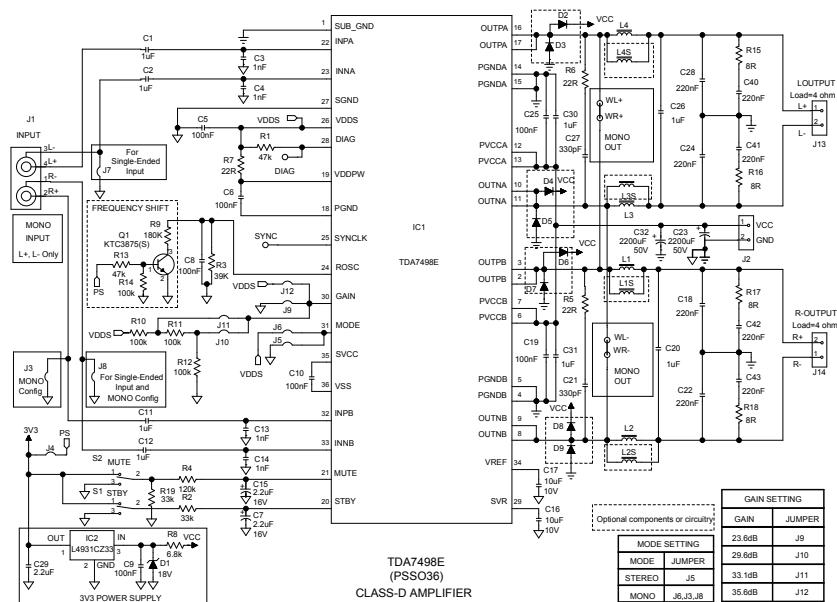
Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
I_q	Total quiescent current	No LC filter, no load	-	60		mA
I_{qSTBY}	Quiescent current in standby	-	-	1		μA
V_{OS}	Output offset voltage	$V_i = 0$, $A_v = 23.6\text{ dB}$, no load	-20	-	20	mV
I_{OCP}	Overcurrent protection threshold	$R_L = 0\ \Omega$	10	11	14	A
T_j	Junction temperature at thermal shutdown	-	140	150	160	°C
R_i	Input resistance	Differential input		69	-	kΩ
V_{UVP}	Undervoltage protection threshold	-	-	-	8	V
R_{dsON}	Power transistor on-resistance	High side	-	0.15	-	Ω

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
(Continued) R _{dsON}	(Continued) Power transistor on-resistance	Low side	-	0.15	-	(Continued) Ω
P _o	Output power	THD = 10%	-	160	-	W
		THD = 1%	-	125	-	
P _o	Parallel BTL (mono) output power, R _L = 3 ohm, V _{cc} = 36 V	THD = 10%	-	220	-	W
		THD = 1%	-	170	-	
η	Efficiency		-	85	-	%
THD	Total harmonic distortion	P _o = 1 W	-	0.05	-	%
G _V	Closed-loop gain	GAIN < 0.25*VDD		23.8		dB
		0.25*VDD < GAIN < 0.5*VDD		29.8		
		0.5*VDD < GAIN < 0.75*VDD		33.3		
		GAIN > 0.75*VDD		35.8		
ΔG _V	Gain matching	-	-1	-	1	dB
C _T	Crosstalk	f = 1 kHz, P _o = 1 W	50	60	-	dB
V _n	Total output noise	Inputs shorted and to ground, A Curve		231		μV
		Inputs shorted and to ground, f = 20 Hz to 20 kHz		400		
SVRR	Supply voltage rejection ratio	fr = 100 Hz, Vr = 0.5 Vpp, C _{SVR} = 10 μF	-	55	-	dB
T _r , T _f	Rise and fall times	-	-	35	-	ns
f _{SW}	Switching frequency	Internal oscillator	240	310	400	kHz
f _{SWR}	Output switching frequency range	With internal oscillator by changing R _{OSC} ⁽¹⁾	240	-		kHz
V _{inH}	Digital input high (H)	-	2.0	-	-	V
V _{inL}	Digital input low (L)		-	-	0.8	
Function mode	Standby & mute & play	STBY < 0.5 V; MUTE = X	Standby			
		STBY > 2.5 V; MUTE < L	Mute			
		STBY > 2.5 V; MUTE > H	Play			
A _{MUTE}	Mute attenuation	V _{MUTE} < L, V _{STBY} = H	-	75	-	dB

1. $f_{SW} = 10^6 / ((16 \cdot R_{OSC} + 182) \cdot 4) \text{ kHz}$, $f_{SYNCLK} = 2 \cdot f_{SW}$ with $R3 = 39 \text{ k}\Omega$ (see Figure 3. Test circuit stereo application and mono BTL mode).

3.5 Test circuit

Figure 3. Test circuit stereo application and mono BTL mode



4 Characterization curves

Unless otherwise stated the measurements were made under the following conditions:

$V_{CC} = 36\text{ V}$, $f = 1\text{ kHz}$, $G_V = 23.6\text{ dB}$, $R_{OSC} = 39\text{ k}\Omega$, $C_{OSC} = 100\text{ nF}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$

4.1 For $R_L = 4\text{ }\Omega$, stereo configuration

Figure 4. Output power vs. supply voltage

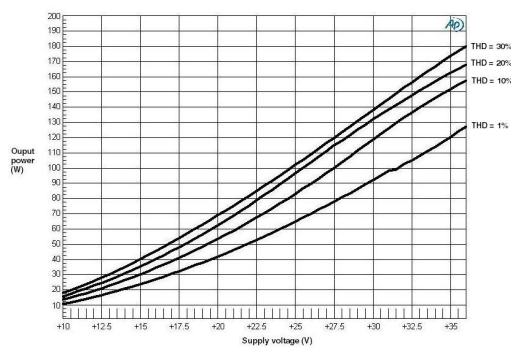


Figure 5. THD vs. output power

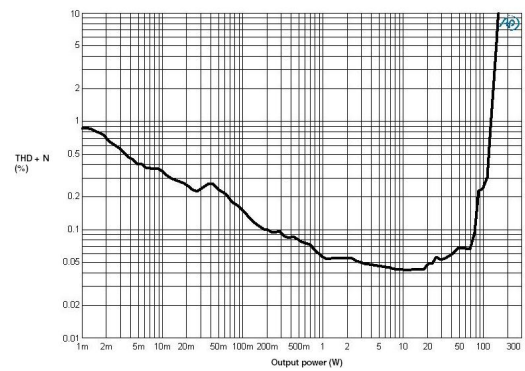


Figure 6. THD vs. frequency

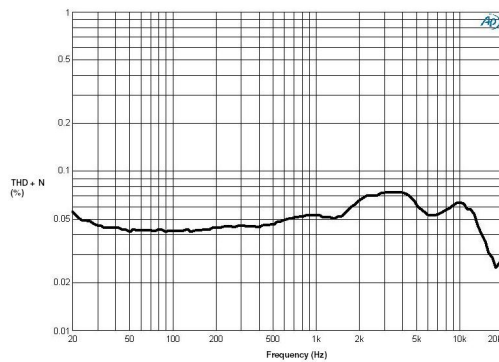


Figure 7. FFT performance

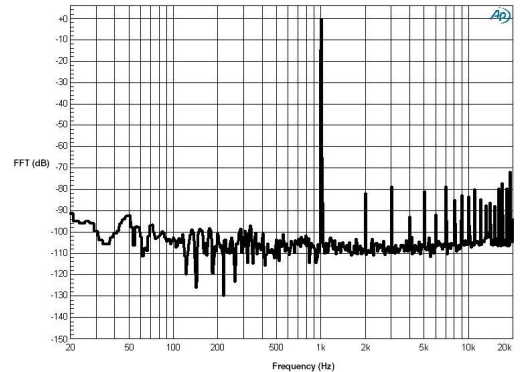
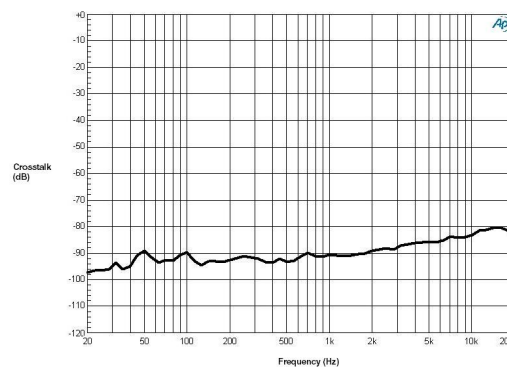
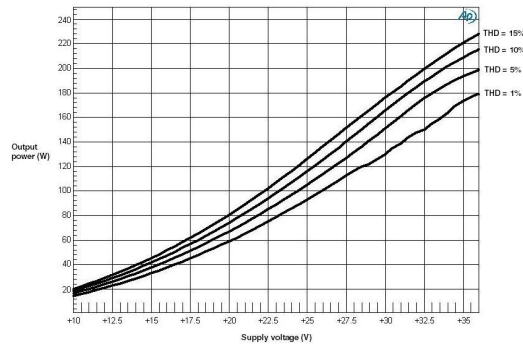
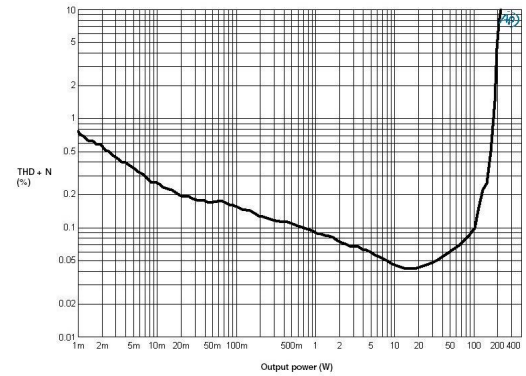
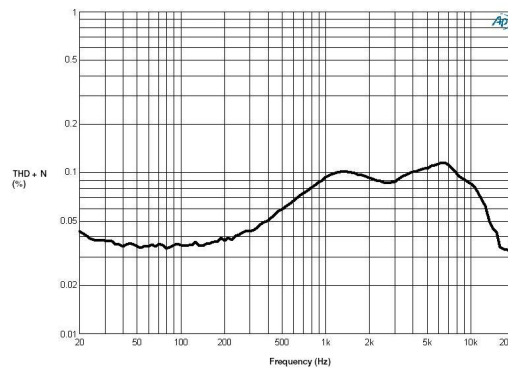


Figure 8. Crosstalk vs. frequency



4.2 For $R_L = 3\ \Omega$, mono BTL configuration

Figure 9. Output power vs. supply voltage

Figure 10. THD vs. output power

Figure 11. THD vs. frequency


5 Application information

5.1 Stereo and mono BTL operation selection using the MODE pin

The TDA7498E can be used in stereo applications or mono BTL applications. Connecting the MODE pin to the VDDS pin configures the device in mono BTL. The output of the two channels can be paralleled. When the MODE pin is connected to ground or floating (pulled down internally) the device works as a stereo amplifier.

5.2 Gain setting

The gain of the TDA7498E is set by GAIN (pin 30).

Table 6. Gain settings

GAIN	Total gain	Application recommendation
$VGAIN < 0.25 \cdot VDDS$	23.6 dB	GAIN pin connected to SGND
$0.25 \cdot VDDS < VGAIN < 0.5 \cdot VDDS$	29.6 dB	$R_{c10} = R_{c11} = R_{c12} = 100 \text{ K max}$
$0.5 \cdot VDDS < VGAIN < 0.75 \cdot VDDS$	33.1 dB	$R_{c10} = R_{c11} = R_{c12} = 100 \text{ K max}$
$VGAIN > 0.75 \cdot VDDS$	35.6 dB	GAIN pin connected to VDDS

5.3 Smart protection

The TDA7498E embeds an overcurrent protection circuitry to protect the device from unwanted current peaks. If the overcurrent protection threshold ([Table 5. Electrical specifications](#)) is exceeded, the power stage will be shut down immediately. The device will recover automatically once the fault is removed.

6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

6.1 PowerSSO-36 EPU package information

Figure 12. PowerSSO-36 EPU package outline

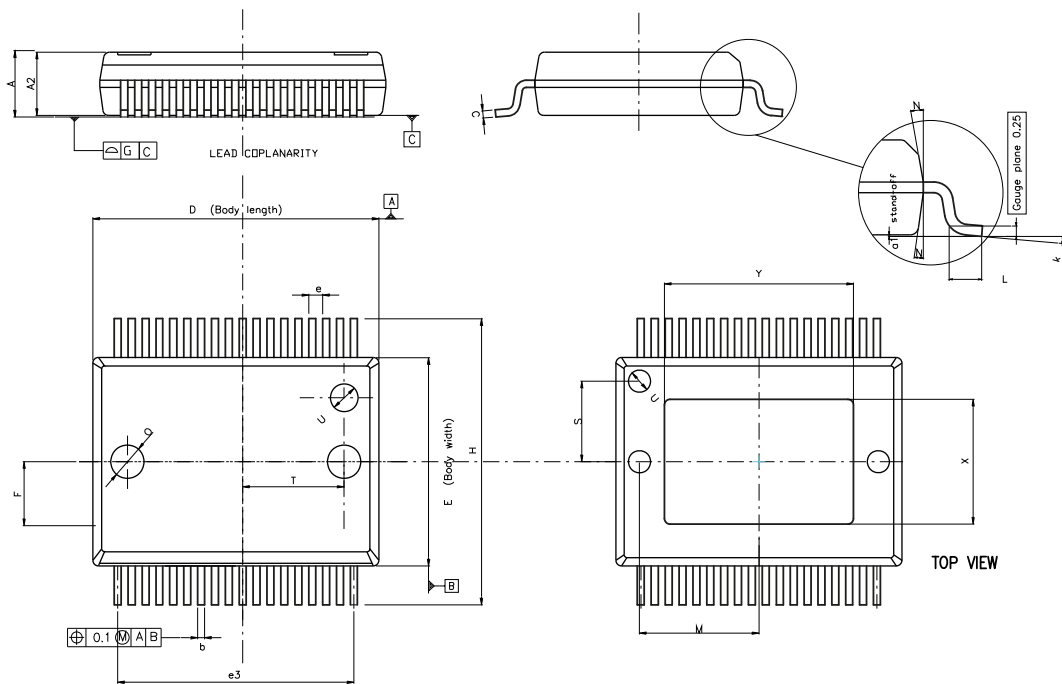


Table 7. PowerSSO-36 EPU package mechanical data

Symbol	mm			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.15	-	2.45	0.085	-	0.096
A2	2.15	-	2.35	0.085	-	0.093
a1	0	-	0.10	0	-	0.004
b	0.18	-	0.36	0.007	-	0.014
c	0.23	-	0.32	0.009	-	0.013
D	10.10	-	10.50	0.398	-	0.413
E	7.40	-	7.60	0.291	-	0.299
e	-	0.5	-	-	0.020	-
e3	-	8.5	-	-	0.335	-
F	-	2.3	-	-	0.091	-
G	-	-	0.10	-	-	0.004
H	10.10	-	10.50	0.398	-	0.413
h	-	-	0.40	-	-	0.016
k	0	-	8 degrees	0	-	8 degrees
L	0.55	-	0.85	0.022	-	0.033
M	-	4.30	-	-	0.169	-
N	-	-	10 degrees	-	-	10 degrees
O	-	1.20	-	-	0.047	-
Q	-	0.80	-	-	0.031	-
S	-	2.90	-	-	0.114	-
T	-	3.65	-	-	0.144	-
U	-	1.00	-	-	0.039	-
X	4.10	-	4.70	0.161	-	0.185
Y	6.50	-	7.10	0.193	-	0.280

Revision history

Table 8. Document revision history

Date	Revision	Changes
12-Dec-2011	1	Initial release.
16-Jun-2015	2	Updated V_{CC} in Table 3: "Absolute maximum ratings" , updated Section 6.3: "Smart protection", and updated dimension L in Table 8: "PowerSSO-36 EPU package mechanical data".
10-Dec-2018	3	Updated device summary on the cover page.
25-Jun-2020	4	Updated Figure 12 and Y min. value in Table 7

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